

Roland Mainz

List of Publications by Year in descending order

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2059
citing authors

| # | ARTICLE | IF | CITATIONS |
|----|--|------|-----------|
| 1 | On the Sn loss from thin films of the material system Cu ₂ ZnSnS ₄ in high vacuum. Journal of Applied Physics, 2010, 107, . | 2.5 | 340 |
| 2 | Gallium gradients in Cu(In,Ga)Se ₂ thin-film solar cells. Progress in Photovoltaics: Research and Applications, 2015, 23, 717-733. | 8.1 | 122 |
| 3 | Phase-transition-driven growth of compound semiconductor crystals from ordered metastable nanorods. Nature Communications, 2014, 5, 3133. | 12.8 | 98 |
| 4 | Real-time observation of Cu ₂ ZnSn(S,Se) ₄ solar cell absorber layer formation from nanoparticle precursors. Physical Chemistry Chemical Physics, 2013, 15, 18281. | 2.8 | 86 |
| 5 | 12.6% efficient CdS/Cu(In,Ga)S ₂ -based solar cell with an open circuit voltage of 879mV prepared by a rapid thermal process. Solar Energy Materials and Solar Cells, 2011, 95, 864-869. | 6.2 | 84 |
| 6 | Comprehensive Comparison of Various Techniques for the Analysis of Elemental Distributions in Thin Films. Microscopy and Microanalysis, 2011, 17, 728-751. | 0.4 | 72 |
| 7 | In ^{in situ} XRD on formation reactions of Cu ₂ ZnSnS ₄ thin films. Physica Status Solidi C: Current Topics in Solid State Physics, 2009, 6, 1245-1248. | 0.8 | 65 |
| 8 | Chemistry and Dynamics of Ge in Kesterite: Toward Band-Gap-Graded Absorbers. Chemistry of Materials, 2017, 29, 9399-9406. | 6.7 | 59 |
| 9 | CdS/Cu(In,Ga)S ₂ based solar cells with efficiencies reaching 12.9% prepared by a rapid thermal process. Progress in Photovoltaics: Research and Applications, 2013, 21, 88-93. | 8.1 | 50 |
| 10 | Time-resolved investigation of Cu(In,Ga)Se ₂ growth and Ga gradient formation during fast selenisation of metallic precursors. Progress in Photovoltaics: Research and Applications, 2015, 23, 1131-1143. | 8.1 | 49 |
| 11 | Compositional and electrical properties of line and planar defects in Cu(In,Ga)Se ₂ thin films for solar cells – a review. Physica Status Solidi - Rapid Research Letters, 2016, 10, 363-375. | 2.4 | 47 |
| 12 | Evolution of opto-electronic properties during film formation of complex semiconductors. Scientific Reports, 2017, 7, 45463. | 3.3 | 47 |
| 13 | Cu ₂ ZnSnS ₄ -based thin films and solar cells by rapid thermal annealing processing. Thin Solid Films, 2017, 628, 1-6. | 1.8 | 45 |
| 14 | Recrystallization of Cu(In,Ga)Se ₂ thin films studied by X-ray diffraction. Acta Materialia, 2013, 61, 4347-4353. | 7.9 | 43 |
| 15 | Annihilation of structural defects in chalcogenide absorber films for high-efficiency solar cells. Energy and Environmental Science, 2016, 9, 1818-1827. | 30.8 | 42 |
| 16 | Effect of precursor stacking order and sulfurization temperature on compositional homogeneity of CZTS thin films. Thin Solid Films, 2016, 615, 402-408. | 1.8 | 41 |
| 17 | Exploiting the features of energy-dispersive synchrotron diffraction for advanced residual stress and texture analysis. Journal of Strain Analysis for Engineering Design, 2011, 46, 615-625. | 1.8 | 39 |
| 18 | Texture inheritance in thin-film growth of Cu ₂ ZnSnS ₄ . Applied Physics Letters, 2009, 95, . | 3.3 | 38 |

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|----|---|------|-----------|
| 19 | Development of CuInS ₂ -based solar cells and modules. <i>Solar Energy Materials and Solar Cells</i> , 2011, 95, 1441-1445. | 6.2 | 37 |
| 20 | Formation of CuInSe ₂ and CuGaSe ₂ Thin Films Deposited by Three-Stage Thermal Co-Evaporation: A Real-Time X-Ray Diffraction and Fluorescence Study. <i>Advanced Energy Materials</i> , 2013, 3, 1381-1387. | 19.5 | 37 |
| 21 | Adjusting the Ga grading during fast atmospheric processing of Cu(In,Ga)Se ₂ solar cell absorber layers using elemental selenium vapor. <i>Progress in Photovoltaics: Research and Applications</i> , 2017, 25, 341-357. | 8.1 | 32 |
| 22 | Sulphurisation of gallium-containing thin-film precursors analysed in-situ. <i>Thin Solid Films</i> , 2007, 515, 5934-5937. | 1.8 | 26 |
| 23 | Combined analysis of spatially resolved electronic structure and composition on a cross-section of a thin film Cu(In _x Ga _{1-x})S ₂ solar cell. <i>Physica Status Solidi (A) Applications and Materials Science</i> , 2009, 206, 1017-1020. | 1.8 | 24 |
| 24 | Real-time study of Ga diffusion processes during the formation of Cu(In,Ga)Se ₂ : The role of Cu and Na content. <i>Solar Energy Materials and Solar Cells</i> , 2013, 116, 102-109. | 6.2 | 24 |
| 25 | Effect of Na presence during CuInSe ₂ growth on stacking fault annihilation and electronic properties. <i>Applied Physics Letters</i> , 2015, 107, . | 3.3 | 23 |
| 26 | Sudden stress relaxation in compound semiconductor thin films triggered by secondary phase segregation. <i>Physical Review B</i> , 2015, 92, . | 3.2 | 22 |
| 27 | In situ analysis of elemental depth distributions in thin films by combined evaluation of synchrotron x-ray fluorescence and diffraction. <i>Journal of Applied Physics</i> , 2011, 109, 123515. | 2.5 | 21 |
| 28 | The role of interparticle heterogeneities in the selenization pathway of Cu-Zn-S nanoparticle thin films: a real-time study. <i>Journal of Materials Chemistry C</i> , 2015, 3, 7128-7134. | 5.5 | 21 |
| 29 | Dependence of phase transitions on halide ratio in inorganic CsPb(Br _x I _{1-x}) ₃ perovskite thin films obtained from high-throughput experimentation. <i>Journal of Materials Chemistry A</i> , 2020, 8, 22626-22631. | 10.3 | 20 |
| 30 | Recrystallization of CuInS thin films studied in situ by energy-dispersive X-ray diffraction. <i>Journal of Applied Crystallography</i> , 2010, 43, 1053-1061. | 4.5 | 18 |
| 31 | Photoelectric characterization of Cu(In,Ga)S ₂ solar cells obtained from rapid thermal processing at different temperatures. <i>Solar Energy Materials and Solar Cells</i> , 2011, 95, 270-273. | 6.2 | 18 |
| 32 | A one-dimensional Fickian model to predict the Ga depth profiles in three-stage Cu(In,Ga)Se ₂ . <i>Journal of Applied Physics</i> , 2014, 115, . | 2.5 | 18 |
| 33 | Photon flux determination of a liquid-metal jet X-ray source by means of photon scattering. <i>Journal of Analytical Atomic Spectrometry</i> , 2019, 34, 1497-1502. | 3.0 | 18 |
| 34 | Diffusion-induced grain boundary migration as mechanism for grain growth and defect annihilation in chalcopyrite thin films. <i>Acta Materialia</i> , 2016, 111, 377-384. | 7.9 | 17 |
| 35 | Current Transport in Cu(In,Ga)S ₂ Based Solar Cells with High Open Circuit Voltage - Bulk vs. Interface. <i>Materials Research Society Symposia Proceedings</i> , 2009, 1165, 1. | 0.1 | 16 |
| 36 | Grazing-incidence x-ray fluorescence analysis for non-destructive determination of In and Ga depth profiles in Cu(In,Ga)Se ₂ absorber films. <i>Applied Physics Letters</i> , 2013, 103, . | 3.3 | 15 |

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|----|--|------|-----------|
| 37 | Elemental redistributions at structural defects in Cu(In,Ga)Se ₂ thin films for solar cells. Journal of Applied Physics, 2016, 120, . | 2.5 | 15 |
| 38 | In-situ studies of the recrystallization process of CuInS ₂ thin films by energy dispersive X-ray diffraction. Thin Solid Films, 2011, 519, 7193-7196. | 1.8 | 13 |
| 39 | Reaction Pathway for Efficient Cu ₂ ZnSnSe ₄ Solar Cells from Alloyed Cu ₂ Sn Precursor via a Cu-Rich Selenization Stage. Solar Rrl, 2020, 4, 2000124. | 5.8 | 13 |
| 40 | Evidence for Cu ₂ Se platelets at grain boundaries and within grains in Cu(In,Ga)Se ₂ thin films. Applied Physics Letters, 2017, 111, . | 3.3 | 12 |
| 41 | Examination of growth kinetics of copper rich Cu(In,Ga)Se ₂ -films using synchrotron energy dispersive X-ray diffractometry. Solar Energy Materials and Solar Cells, 2011, 95, 250-253. | 6.2 | 11 |
| 42 | Point defect segregation and its role in the detrimental nature of Frank partials in Cu(In,Ga)Se ₂ thin-film absorbers. Physical Review B, 2017, 95, . | 3.2 | 11 |
| 43 | Advanced characterization and in-situ growth monitoring of Cu(In,Ga)Se ₂ thin films and solar cells. Solar Energy, 2018, 170, 102-112. | 6.1 | 11 |
| 44 | High voltage Cu(In,Ga)S ₂ solar modules. Thin Solid Films, 2011, 519, 7534-7536. | 1.8 | 10 |
| 45 | The complex material properties of chalcopyrite and kesterite thin-film solar cell absorbers tackled by synchrotron-based analytics. Progress in Photovoltaics: Research and Applications, 2012, 20, 557-567. | 8.1 | 10 |
| 46 | Lateral phase separation in Cu-In-Ga precursor and Cu(In,Ga)Se ₂ absorber thin films. Solar Energy Materials and Solar Cells, 2017, 162, 120-126. | 6.2 | 10 |
| 47 | Stacking fault reduction during annealing in Cu-poor CuInSe ₂ thin film solar cell absorbers analyzed by in situ XRD and grain growth modeling. Journal of Applied Physics, 2019, 125, . | 2.5 | 10 |
| 48 | Phase and film formation pathway for vacuum-deposited Cu ₂ BaSn(S,Se) ₄ absorber layers. Physical Review Materials, 2019, 3, . | 2.4 | 10 |
| 49 | High-temperature decomposition of Cu ₂ BaSnS ₄ with Sn loss reveals newly identified compound Cu ₂ Ba ₃ Sn ₂ S ₈ . Journal of Materials Chemistry A, 2020, 8, 11346-11353. | 10.3 | 8 |
| 50 | Recrystallization of Cu-poor CuInS ₂ assisted by metallic Cu or Ag. Journal of Solid State Chemistry, 2010, 183, 803-806. | 2.9 | 7 |
| 51 | Influence of precursor stacking on the absorber growth in Cu(In,Ga)S ₂ based solar cells prepared by a rapid thermal process. Thin Solid Films, 2011, 519, 7189-7192. | 1.8 | 7 |
| 52 | Fast Cu(In, Ga)Se ₂ formation by processing Cu-In-Ga precursors in selenium atmosphere. , 2011, , . | | 7 |
| 53 | Traceable Quantitative Raman Microscopy and X-ray Fluorescence Analysis as Nondestructive Methods for the Characterization of Cu(In,Ga)Se ₂ Absorber Films. Applied Spectroscopy, 2016, 70, 279-288. | 2.2 | 6 |
| 54 | Phototransport Properties of Cu(In,Ga)Se ₂ Thin Films: The Influence of Na and Planar Defects. Physical Review Applied, 2020, 14, . | 3.8 | 6 |

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|----|---|------|-----------|
| 55 | Neutrons and Photons in Materials Research for Thin Film Solar Cells. Advanced Engineering Materials, 2011, 13, 737-741. | 3.5 | 5 |
| 56 | Selenization of CuInS_2 by rapid thermal processing – an alternative approach to induce a band gap grading in chalcopyrite thin-film solar cell absorbers?. Journal of Materials Chemistry A, 2019, 7, 2087-2094. | 10.3 | 5 |
| 57 | Secondary-Phase-Assisted Grain Boundary Migration in CuInSe_2 . Physical Review Letters, 2020, 124, 095702. | 7.8 | 5 |
| 58 | Effects of material properties of band-gap-graded $\text{Cu}(\text{In,Ga})\text{Se}_2$ thin films on the onset of the quantum efficiency spectra of corresponding solar cells. Progress in Photovoltaics: Research and Applications, 2022, 30, 1238-1246. | 8.1 | 5 |
| 59 | In-situ observations of recrystallization in CuInSe_2 solar cells via STEM. Microscopy and Microanalysis, 2018, 24, 1492-1493. | 0.4 | 4 |
| 60 | Co-evaporation of $\text{Cu}(\text{In, Ga})\text{Se}_2$ at low temperatures: An In-Situ x-ray growth analysis. , 2013, , . | | 3 |
| 61 | Investigation of near-stoichiometric polycrystalline CuInSe_2 thin films by photoreflectance spectroscopy. Journal of Applied Physics, 2020, 127, 125701. | 2.5 | 3 |
| 62 | Copper Sulfide Assisted Recrystallization of Cu-poor CuInS_2 Observed in-situ by Polychromatic X-ray Diffraction. Materials Research Society Symposia Proceedings, 2009, 1165, 1. Stress Formation During $\text{In} - \text{Ga}$ Interdiffusion in Thin-Film | 0.1 | 2 |
| 63 | Ga Interdiffusion in Thin-Film $\text{Cu}(\text{In,Ga})\text{Se}_2$ Thin Films. Physica Status Solidi - Rapid Research Letters, 2021, 15, 2100042. | 3.8 | 2 |
| 64 | Optoelectronic Inactivity of Dislocations in $\text{Cu}(\text{In,Ga})\text{Se}_2$ Thin Films. Physica Status Solidi - Rapid Research Letters, 2021, 15, 2100042. | 2.4 | 2 |
| 65 | Radiative recombination properties of near-stoichiometric CuInS_2 thin films. Physical Review Materials, 2020, 4, . | 2.4 | 2 |
| 66 | In-situ monitoring of rapid thermal processes (RTP) OF $\text{Cu}(\text{IN,GA})(\text{S,SE})_2$ by optical methods. Proceedings of SPIE, 2008, , . | 0.8 | 1 |
| 67 | Real-time observation of the phase transformations and microstructural changes during the incorporation of In into a thin Cu film at 770K. Journal of Alloys and Compounds, 2014, 588, 644-647. | 5.5 | 1 |
| 68 | Atomic-Scale STEM-EELS Characterization of the Chemistry of Structural Defects and Interfaces in Energy-Related Materials. Microscopy and Microanalysis, 2014, 20, 562-563. | 0.4 | 0 |
| 69 | Linking Microstructure and Local Chemistry in $\text{Cu}(\text{In,Ga})\text{Se}_2$ Thin-Film Solar Cells. Microscopy and Microanalysis, 2015, 21, 2279-2280. | 0.4 | 0 |
| 70 | Modulation spectroscopy characterization of Cu based chalcopyrites and kesterites. , 2018, , . | | 0 |
| 71 | Defect Annihilation by Preferential Grain Growth during $\text{Cu}(\text{In,Ga})\text{Se}_2$ Co-evaporation. , 2018, , . | | 0 |